

# 74ALVT16244

16-bit buffer/line driver; 3-state

Rev. 5 — 2 February 2018

Product data sheet

## 1 General description

The 74ALVT16244 is a high-performance BiCMOS product designed for  $V_{CC}$  operation at 2.5V or 3.3V with I/O compatibility up to 5V.

This device is a 16-bit buffer and line driver featuring non-inverting 3-state bus outputs. The device can be used as four 4-bit buffers, two 8-bit buffers, or one 16-bit buffer.

## 2 Features and benefits

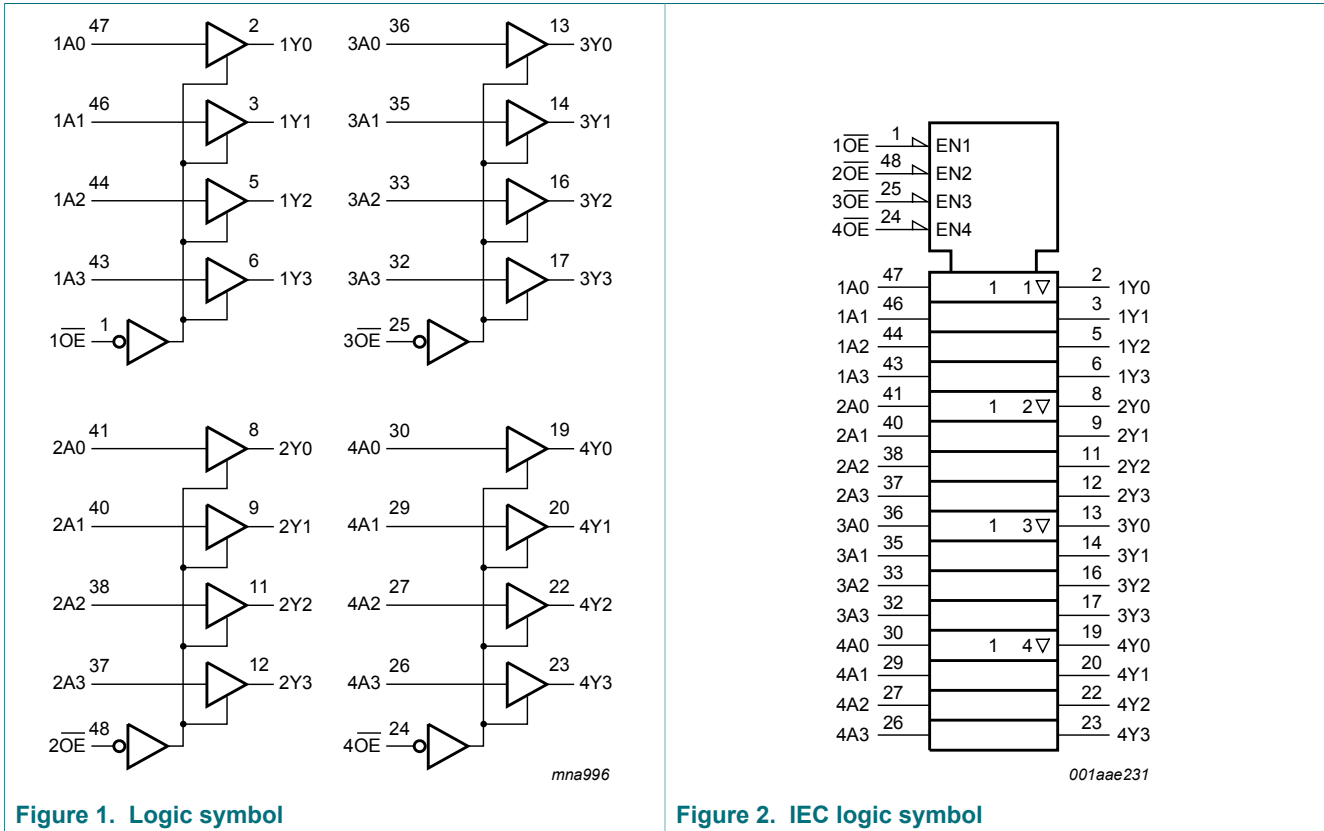
- 16-bit bus interface
- 3-State buffers
- 5V I/O compatible
- Output capability: +64 mA/-32 mA
- TTL input and output switching levels
- Input and output interface capability to systems at 5 V supply
- Bus-hold data inputs eliminate the need for external pull-up resistors to hold unused inputs
- Live insertion/extraction permitted
- Power-up 3-State
- No bus current loading when output is tied to 5 V bus
- Latch-up protection:
  - JESD17: exceeds 500 mA
- ESD protection:
  - MIL STD 883 method 3015: exceeds 2000 V
  - MM exceeds 200 V

## 3 Ordering information

Table 1. Ordering information

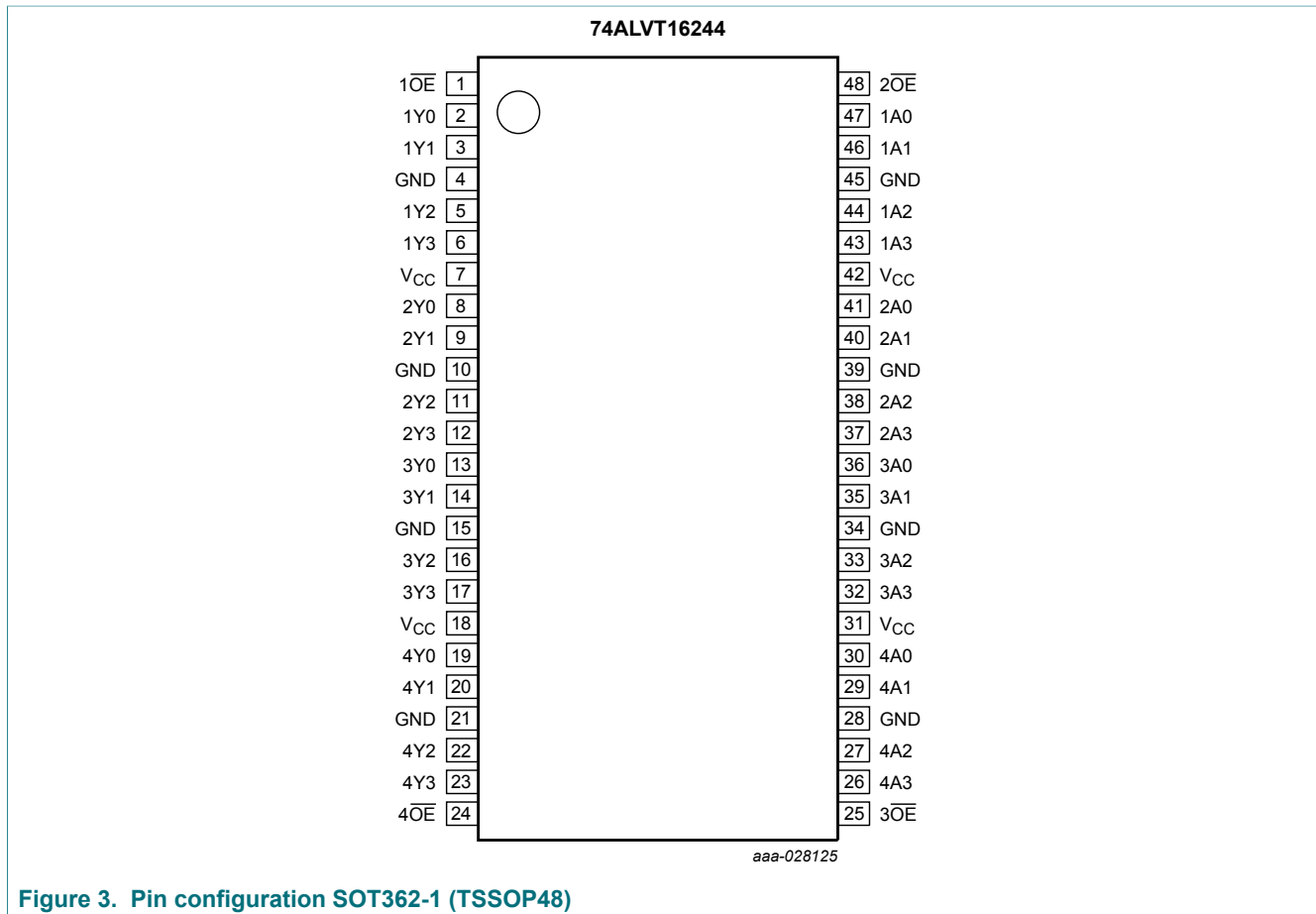
| Type number    | Package           |         |  |          |
|----------------|-------------------|---------|--|----------|
|                | Temperature range | Name    | Description  | Version  |
| 74ALVT16244DGG | -40 °C to +85 °C  | TSSOP48 | plastic thin shrink small outline package; 48 leads; body width 6.1 mm | SOT362-1 |

### 4 Functional diagram



## 5 Pinning information

### 5.1 Pinning



**Figure 3. Pin configuration SOT362-1 (TSSOP48)**

## 5.2 Pin description

Table 2. Pin description

| Symbol  | Pin                           | Description                       |
|---|-------------------------------|-----------------------------------|
| 1 $\overline{O}E$ , 2 $\overline{O}E$ , 3 $\overline{O}E$ , 4 $\overline{O}E$ | 1, 48, 25, 24                 | output enable inputs (active LOW) |
| 1A0, 1A1, 1A2, 1A3  | 47, 46, 44, 43                | data inputs                       |
| 2A0, 2A1, 2A2, 2A3  | 41, 40, 38, 37                | data inputs                       |
| 3A0, 3A1, 3A2, 3A3  | 36, 35, 33, 32                | data inputs                       |
| 4A0, 4A1, 4A2, 4A3  | 30, 29, 27, 26                | data inputs                       |
| 1Y0, 1Y1, 1Y2, 1Y3  | 2, 3, 5, 6                    | data outputs                      |
| 2Y0, 2Y1, 2Y2, 2Y3  | 8, 9, 11, 12                  | data outputs                      |
| 3Y0, 3Y1, 3Y2, 3Y3  | 13, 14, 16, 17                | data outputs                      |
| 4Y0, 4Y1, 4Y2, 4Y3  | 19, 20, 22, 23                | data outputs                      |
| GND   | 4, 10, 15, 21, 28, 34, 39, 45 | ground (0 V)                      |
| V <sub>CC</sub>   | 7, 18, 31, 42                 | supply voltage                    |

## 6 Functional description

Table 3. Function table

*H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.*

| Input             |     | Output |
|-------------------|-----|--------|
| n $\overline{O}E$ | nAn | nYn    |
| L                 | L   | L      |
| L                 | H   | H      |
| H                 | X   | Z      |

## 7 Limiting values

**Table 4. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol    | Parameter               | Conditions                        | Min      | Max  | Unit |
|-----------|-------------------------|-----------------------------------|----------|------|------|
| $V_{CC}$  | supply voltage          |                                   | -0.5     | +4.6 | V    |
| $V_I$     | input voltage           |                                   | [1] -0.5 | +7.0 | V    |
| $V_O$     | output voltage          | output in OFF-state or HIGH-state | [1] -0.5 | +7.0 | V    |
| $I_{IK}$  | input clamping current  | $V_I < 0$ V                       | -50      | -    | mA   |
| $I_{OK}$  | output clamping current | $V_O < 0$ V                       | -50      | -    | mA   |
| $I_O$     | output current          | output in LOW-state               | -        | 128  | mA   |
|           |                         | output in HIGH-state              | -64      | -    | mA   |
| $T_{stg}$ | storage temperature     |                                   | -65      | +150 | °C   |
| $T_j$     | junction temperature    |                                   | [2] -    | 150  | °C   |

[1] The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

[2] The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability.

## 8 Recommended operating conditions

**Table 5. Recommended operating conditions**

| Symbol              | Parameter                           | Conditions  | $V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$ |     | $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$ |     | Unit |
|---------------------|-------------------------------------|---|--|-----|--|-----|------|
|                     |                                     |   | Min  | Max | Min  | Max |      |
| $V_{CC}$            | supply voltage                      |   | 2.3  | 2.7 | 3.0  | 3.6 | V    |
| $V_I$               | input voltage                       |   | 0  | 5.5 | 0  | 5.5 | V    |
| $I_{OH}$            | HIGH-level output current           |   | -  | -8  | -  | -32 | mA   |
| $I_{OL}$            | LOW-level output current            | none  | -  | 8   | -  | 32  | mA   |
|                     |                                     | current duty cycle $\leq 50$ %;<br>$f_i \geq 1$ kHz | -  | 24  | -  | 64  | mA   |
| $\Delta t/\Delta V$ | input transition rise and fall rate | outputs enabled                                     | -  | 10  | -  | 10  | ns/V |
| $T_{amb}$           | ambient temperature                 | free-air  | -40  | +85 | -40  | +85 | °C   |

## 9 Static characteristics

**Table 6. Static characteristics**

At recommended operating conditions;  $T_{amb} = -40$  °C to +85 °C ; voltages are referenced to GND (ground = 0 V).

| Symbol   | Parameter                | Conditions   | Min | Typ <sup>[1]</sup> | Max  | Unit |
|--|--------------------------|--|-----|--------------------|------|------|
| <b><math>V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}</math></b> |                          |  |     |                    |      |      |
| $V_{IK}$   | input clamping voltage   | $V_{CC} = 2.3 \text{ V}$ ; $I_{IK} = -18 \text{ mA}$ | -   | -0.85              | -1.2 | V    |
| $V_{IH}$   | HIGH-level input voltage | $V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$           | 1.7 | -                  | -    | V    |
| $V_{IL}$   | LOW-level input voltage  | $V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$           | -   | -                  | 0.7  | V    |

| Symbol                                | Parameter                          | Conditions  | Min                   | Typ <sup>[1]</sup> | Max  | Unit |
|---------------------------------------|------------------------------------|---|-----------------------|--------------------|------|------|
| V <sub>OH</sub>                       | HIGH-level output voltage          | V <sub>CC</sub> = 2.5 V ± 0.2 V; I <sub>O</sub> = -100 μA   | V <sub>CC</sub> - 0.2 | V <sub>CC</sub>    | -    | V    |
|                                       |                                    | V <sub>CC</sub> = 2.3 V; I <sub>O</sub> = -8 mA   | 1.8                   | 2.5                | -    | V    |
| V <sub>OL</sub>                       | LOW-level output voltage           | V <sub>CC</sub> = 2.3 V; I <sub>O</sub> = 100 μA  | -                     | 0.07               | 0.2  | V    |
|                                       |                                    | V <sub>CC</sub> = 2.3 V; I <sub>O</sub> = 24 mA   | -                     | 0.3                | 0.5  | V    |
| I <sub>I</sub>                        | input leakage current              | all input pins <sup>[2]</sup>   |                       |                    |      |      |
|                                       |                                    | V <sub>CC</sub> = 0 V or 2.7 V; V <sub>I</sub> = 5.5 V  | -                     | 0.1                | 10   | μA   |
|                                       |                                    | control pins  |                       |                    |      |      |
|                                       |                                    | V <sub>CC</sub> = 2.7 V; V <sub>I</sub> = V <sub>CC</sub> or GND  | -                     | 0.1                | ±1   | μA   |
|                                       |                                    | data pins; <sup>[2]</sup>   |                       |                    |      |      |
|                                       |                                    | V <sub>CC</sub> = 2.7 V; V <sub>I</sub> = V <sub>CC</sub>   | -                     | 0.1                | 1    | μA   |
|                                       |                                    | V <sub>CC</sub> = 2.7 V; V <sub>I</sub> = 0 V   | -                     | 0.1                | -5   | μA   |
| I <sub>OFF</sub>                      | power-off leakage current          | V <sub>CC</sub> = 0 V; V <sub>I</sub> or V <sub>O</sub> = 0 V to 4.5 V  | -                     | 0.1                | ±100 | μA   |
| I <sub>BHL</sub>                      | bus hold LOW current               | data inputs; V <sub>CC</sub> = 2.3 V; V <sub>I</sub> = 0.7 V <sup>[3]</sup>   | -                     | 115                | -    | μA   |
| I <sub>BHH</sub>                      | bus hold HIGH current              | data inputs; V <sub>CC</sub> = 2.3 V; V <sub>I</sub> = 1.7 V <sup>[3]</sup>   | -                     | -10                | -    | μA   |
| I <sub>EX</sub>                       | external current                   | output in HIGH-state when V <sub>O</sub> > V <sub>CC</sub> ;<br>V <sub>O</sub> = 5.5 V; V <sub>CC</sub> = 2.3 V   | -                     | 10                 | 125  | μA   |
| I <sub>O(pu/pd)</sub>                 | power-up/power-down output current | V <sub>CC</sub> ≤ 1.2 V; V <sub>O</sub> = 0.5 V to V <sub>CC</sub> ;<br>V <sub>I</sub> = GND or V <sub>CC</sub> ; n $\overline{OE}$ = don't care <sup>[4]</sup> | -                     | 1                  | ±100 | μA   |
| I <sub>OZ</sub>                       | OFF-state output current           | V <sub>CC</sub> = 2.7 V; V <sub>I</sub> = V <sub>IL</sub> or V <sub>IH</sub>  |                       |                    |      |      |
|                                       |                                    | output HIGH: V <sub>O</sub> = 2.3V  | -                     | 0.5                | 5    | μA   |
|                                       |                                    | output LOW: V <sub>O</sub> = 0.5 V  | -                     | 0.5                | -5   | μA   |
| I <sub>CC</sub>                       | supply current                     | V <sub>CC</sub> = 2.7 V; V <sub>I</sub> = GND or V <sub>CC</sub> ; I <sub>O</sub> = 0 A   |                       |                    |      |      |
|                                       |                                    | outputs HIGH  | -                     | 0.04               | 0.1  | mA   |
|                                       |                                    | outputs LOW   | -                     | 2.5                | 4.5  | mA   |
|                                       |                                    | outputs disabled <sup>[5]</sup>   | -                     | 0.04               | 0.1  | mA   |
| ΔI <sub>CC</sub>                      | additional supply current          | per input pin; V <sub>CC</sub> = 2.3 V to 2.7 V;<br>one input at V <sub>CC</sub> - 0.6 V;<br>other inputs at V <sub>CC</sub> or GND <sup>[6]</sup>              | -                     | 0.04               | 0.4  | mA   |
| C <sub>I</sub>                        | input capacitance                  | n $\overline{OE}$ ; V <sub>I</sub> = 0 V or V <sub>CC</sub>   | -                     | 3                  | -    | pF   |
| C <sub>O</sub>                        | output capacitance                 | V <sub>O</sub> = 0 V or V <sub>CC</sub>   | -                     | 9                  | -    | pF   |
| <b>V<sub>CC</sub> = 3.3 V ± 0.3 V</b> |                                    |   |                       |                    |      |      |
| V <sub>IK</sub>                       | input clamping voltage             | V <sub>CC</sub> = 3.0 V; I <sub>IK</sub> = -18 mA   | -                     | -0.85              | -1.2 | V    |
| V <sub>IH</sub>                       | HIGH-level input voltage           | V <sub>CC</sub> = 3.3 V ± 0.3 V   | 2.0                   | -                  | -    | V    |
| V <sub>IL</sub>                       | LOW-level input voltage            | V <sub>CC</sub> = 3.3 V ± 0.3 V   | -                     | -                  | 0.8  | V    |
| V <sub>OH</sub>                       | HIGH-level output voltage          | V <sub>CC</sub> = 3.3 V ± 0.3 V; I <sub>O</sub> = -100 μA   | V <sub>CC</sub> - 0.2 | V <sub>CC</sub>    | -    | V    |
|                                       |                                    | V <sub>CC</sub> = 3.0 V; I <sub>O</sub> = -32 mA  | 2.0                   | 2.3                | -    | V    |

| Symbol                | Parameter                          | Conditions  | Min  | Typ <sup>[1]</sup> | Max  | Unit |
|-----------------------|------------------------------------|---|------|--------------------|------|------|
| V <sub>OL</sub>       | LOW-level output voltage           | V <sub>CC</sub> = 3.0 V; I <sub>O</sub> = 100 μA  | -    | 0.07               | 0.2  | V    |
|                       |                                    | V <sub>CC</sub> = 3.0 V; I <sub>O</sub> = 16 mA   | -    | 0.25               | 0.4  | V    |
|                       |                                    | V <sub>CC</sub> = 3.0 V; I <sub>O</sub> = 32 mA   | -    | 0.3                | 0.5  | V    |
|                       |                                    | V <sub>CC</sub> = 3.0 V; I <sub>O</sub> = 64 mA   | -    | 0.4                | 0.55 | V    |
| I <sub>I</sub>        | input leakage current              | all input pins <sup>[2]</sup>   |      |                    |      |      |
|                       |                                    | V <sub>CC</sub> = 0 V or 3.6 V; V <sub>I</sub> = 5.5 V  | -    | 0.1                | 10   | μA   |
|                       |                                    | control pins  |      |                    |      |      |
|                       |                                    | V <sub>CC</sub> = 3.6 V; V <sub>I</sub> = V <sub>CC</sub> or GND  | -    | 0.1                | ±1   | μA   |
|                       |                                    | data pins <sup>[2]</sup>  |      |                    |      |      |
|                       |                                    | V <sub>CC</sub> = 3.6 V; V <sub>I</sub> = V <sub>CC</sub>   | -    | 0.5                | 1    | μA   |
|                       |                                    | V <sub>CC</sub> = 3.6 V; V <sub>I</sub> = 0 V   | -    | 0.1                | -5   | μA   |
| I <sub>OFF</sub>      | power-off leakage current          | V <sub>CC</sub> = 0 V; V <sub>I</sub> or V <sub>O</sub> = 0 V to 4.5 V  | -    | 0.1                | ±100 | μA   |
| I <sub>BHL</sub>      | bus hold LOW current               | data inputs; V <sub>CC</sub> = 3 V; V <sub>I</sub> = 0.8 V  | 75   | 130                | -    | μA   |
| I <sub>BHH</sub>      | bus hold HIGH current              | data inputs; V <sub>CC</sub> = 3 V; V <sub>I</sub> = 2.0 V  | -75  | -140               | -    | μA   |
| I <sub>BHLO</sub>     | bus hold LOW overdrive current     | data inputs; V <sub>CC</sub> = 3.6 V; V <sub>I</sub> = 0 V to 3.6 V <sup>[7]</sup>  | 500  | -                  | -    | μA   |
| I <sub>BHHO</sub>     | bus hold HIGH overdrive current    | data inputs; V <sub>CC</sub> = 3.6 V; V <sub>I</sub> = 0 V to 3.6 V <sup>[7]</sup>  | -500 | -                  | -    | μA   |
| I <sub>EX</sub>       | external current                   | output in HIGH-state when V <sub>O</sub> > V <sub>CC</sub> ;<br>V <sub>O</sub> = 5.5 V; V <sub>CC</sub> = 3.0 V   | -    | 10                 | 125  | μA   |
| I <sub>O(pu/pd)</sub> | power-up/power-down output current | V <sub>CC</sub> ≤ 1.2 V; V <sub>O</sub> = 0.5 V to V <sub>CC</sub> ;<br>V <sub>I</sub> = GND or V <sub>CC</sub> ; n <sub>OE</sub> = don't care <sup>[8]</sup> | -    | 1                  | ±100 | μA   |
| I <sub>OZ</sub>       | OFF-state output current           | V <sub>CC</sub> = 3.6 V; V <sub>I</sub> = V <sub>IL</sub> or V <sub>IH</sub>  |      |                    |      |      |
|                       |                                    | output HIGH: V <sub>O</sub> = 3.0V  | -    | 0.5                | 5    | μA   |
|                       |                                    | output LOW: V <sub>O</sub> = 0.5 V  | -    | 0.5                | -5   | μA   |
| I <sub>CC</sub>       | supply current                     | V <sub>CC</sub> = 3.6 V; V <sub>I</sub> = GND or V <sub>CC</sub> ; I <sub>O</sub> = 0 A   |      |                    |      |      |
|                       |                                    | outputs HIGH  | -    | 0.05               | 0.1  | mA   |
|                       |                                    | outputs LOW   | -    | 3.6                | 5    | mA   |
|                       |                                    | outputs disabled <sup>[5]</sup>   | -    | 0.06               | 0.1  | mA   |
| ΔI <sub>CC</sub>      | additional supply current          | per input pin; V <sub>CC</sub> = 3 V to 3.6 V;<br>one input at V <sub>CC</sub> - 0.6 V;<br>other inputs at V <sub>CC</sub> or GND <sup>[6]</sup>              | -    | 0.04               | 0.4  | mA   |
| C <sub>I</sub>        | input capacitance                  | n <sub>OE</sub> ; V <sub>I</sub> = 0 V or V <sub>CC</sub>   | -    | 3                  | -    | pF   |
| C <sub>O</sub>        | output capacitance                 | V <sub>O</sub> = 0 V or V <sub>CC</sub>   | -    | 9                  | -    | pF   |

[1] Typical values for V<sub>CC</sub> = 2.5 V ± 0.2 V are measured at V<sub>CC</sub> = 2.5 V and T<sub>amb</sub> = 25 °C.

Typical values for V<sub>CC</sub> = 3.3 V ± 0.3 V are measured at V<sub>CC</sub> = 3.3 V and T<sub>amb</sub> = 25 °C.

[2] Unused pins at V<sub>CC</sub> or GND.

[3] Not guaranteed.

[4] This parameter is valid for any V<sub>CC</sub> between 0 V and 1.2 V with a transition time of up to 10 ms.

From V<sub>CC</sub> = 1.2 V to V<sub>CC</sub> = 2.5 V ± 0.2 V a transition time of 100 μs is permitted. This parameter is valid for T<sub>amb</sub> = 25 °C only.

[5] I<sub>CC</sub> is measured with outputs pulled to V<sub>CC</sub> or GND.

[6] This is the increase in supply current for each input at the specified voltage level other than V<sub>CC</sub> or GND.

[7] This is the bus hold overdrive current required to force the input to the opposite logic state.

[8] This parameter is valid for any V<sub>CC</sub> between 0 V and 1.2 V with a transition time of up to 10 ms.

From V<sub>CC</sub> = 1.2 V to V<sub>CC</sub> = 3.3 V ± 0.3 V a transition time of 100 μs is permitted. This parameter is valid for T<sub>amb</sub> = 25 °C only.

## 10 Dynamic characteristics

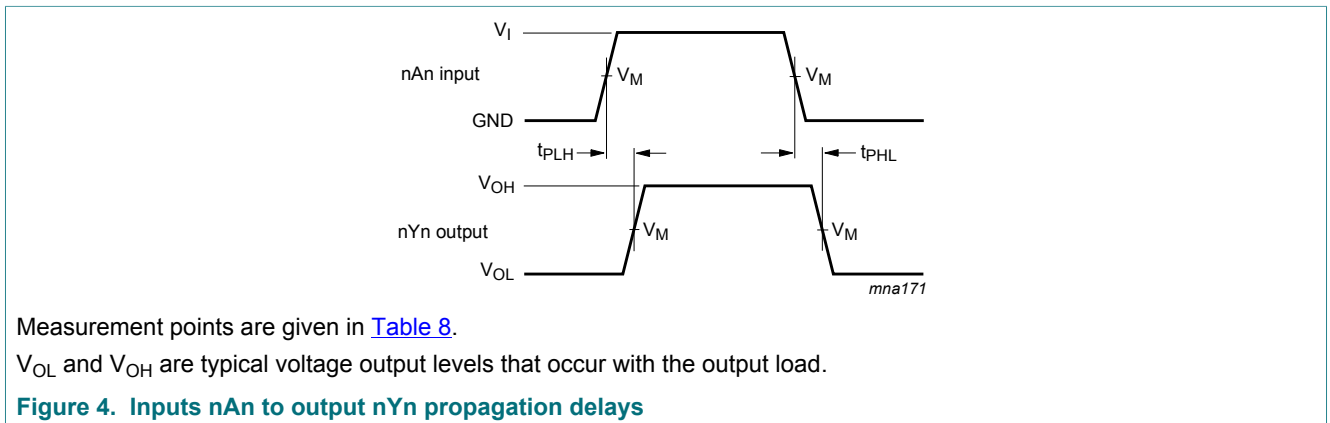
**Table 7. Dynamic characteristics**

Voltages are referenced to GND (ground = 0 V);  $T_{amb} = -40\text{ °C}$  to  $+85\text{ °C}$ ; for test circuit see [Figure 6](#).

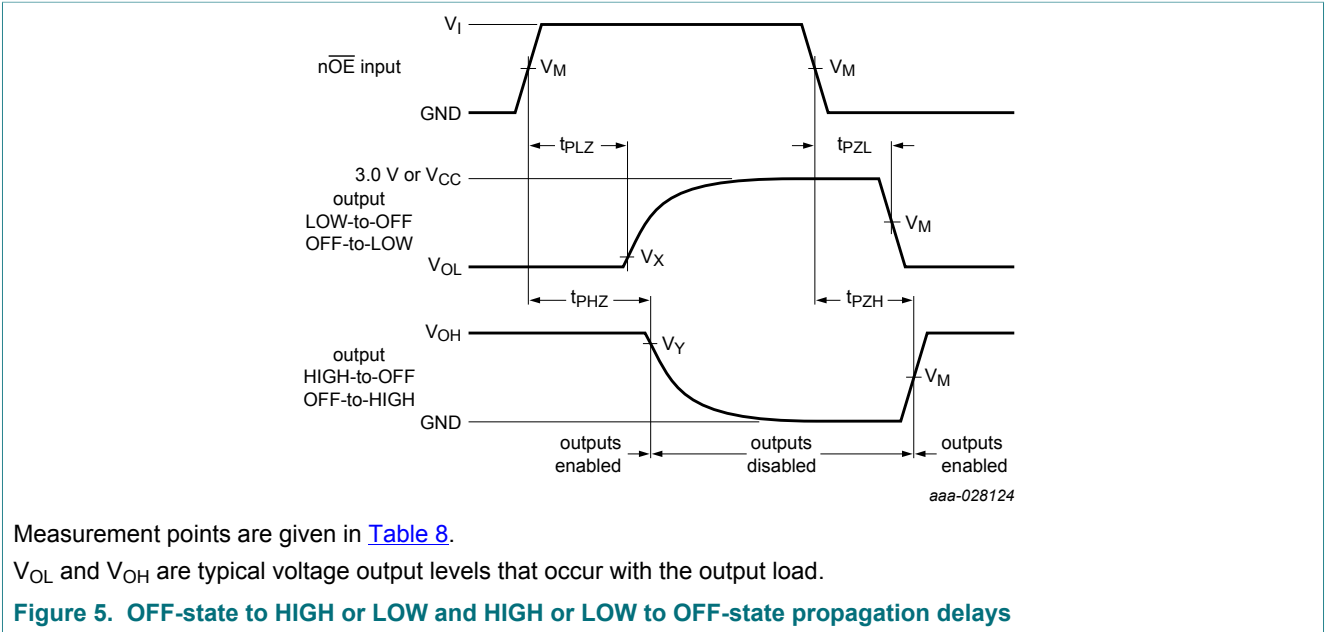
| Symbol   | Parameter                           | Conditions  | Min | Typ <sup>[1]</sup> | Max | Unit |
|--|-------------------------------------|---|-----|--------------------|-----|------|
| <b><math>V_{CC} = 2.5\text{ V} \pm 0.2\text{ V}</math></b> |                                     |   |     |                    |     |      |
| $t_{PLH}$  | LOW to HIGH propagation delay       | nAn to nYn; see <a href="#">Figure 4</a>              | 1.0 | 1.8                | 3.0 | ns   |
| $t_{PHL}$  | HIGH to LOW propagation delay       | nAn to nYn; see <a href="#">Figure 4</a>              | 1.0 | 1.9                | 3.5 | ns   |
| $t_{PZH}$  | OFF-state to HIGH propagation delay | $\overline{nOE}$ to nYn; see <a href="#">Figure 5</a> | 2.0 | 3.1                | 5.9 | ns   |
| $t_{PZL}$  | OFF-state to LOW propagation delay  | $\overline{nOE}$ to nYn; see <a href="#">Figure 5</a> | 1.5 | 2.5                | 4.7 | ns   |
| $t_{PHZ}$  | HIGH to OFF-state propagation delay | $\overline{nOE}$ to nYn; see <a href="#">Figure 5</a> | 1.5 | 2.7                | 4.4 | ns   |
| $t_{PLZ}$  | LOW to OFF-state propagation delay  | $\overline{nOE}$ to nYn; see <a href="#">Figure 5</a> | 1.0 | 2.0                | 3.4 | ns   |
| <b><math>V_{CC} = 3.3\text{ V} \pm 0.3\text{ V}</math></b> |                                     |   |     |                    |     |      |
| $t_{PLH}$  | LOW to HIGH propagation delay       | nAn to nYn; see <a href="#">Figure 4</a>              | 0.8 | 1.5                | 2.4 | ns   |
| $t_{PHL}$  | HIGH to LOW propagation delay       | nAn to nYn; see <a href="#">Figure 4</a>              | 0.8 | 1.5                | 2.5 | ns   |
| $t_{PZH}$  | OFF-state to HIGH propagation delay | $\overline{nOE}$ to nYn; see <a href="#">Figure 5</a> | 1.0 | 2.3                | 3.8 | ns   |
| $t_{PZL}$  | OFF-state to LOW propagation delay  | $\overline{nOE}$ to nYn; see <a href="#">Figure 5</a> | 0.5 | 1.8                | 2.9 | ns   |
| $t_{PHZ}$  | HIGH to OFF-state propagation delay | $\overline{nOE}$ to nYn; see <a href="#">Figure 5</a> | 1.5 | 2.7                | 4.2 | ns   |
| $t_{PLZ}$  | LOW to OFF-state propagation delay  | $\overline{nOE}$ to nYn; see <a href="#">Figure 5</a> | 1.5 | 2.3                | 3.6 | ns   |

[1] Typical values for  $V_{CC} = 2.5\text{ V} \pm 0.2\text{ V}$  are measured at  $V_{CC} = 2.5\text{ V}$  and  $T_{amb} = 25\text{ °C}$ .  
 Typical values for  $V_{CC} = 3.3\text{ V} \pm 0.3\text{ V}$  are measured at  $V_{CC} = 3.3\text{ V}$  and  $T_{amb} = 25\text{ °C}$ .

### 10.1 Waveforms and test circuit

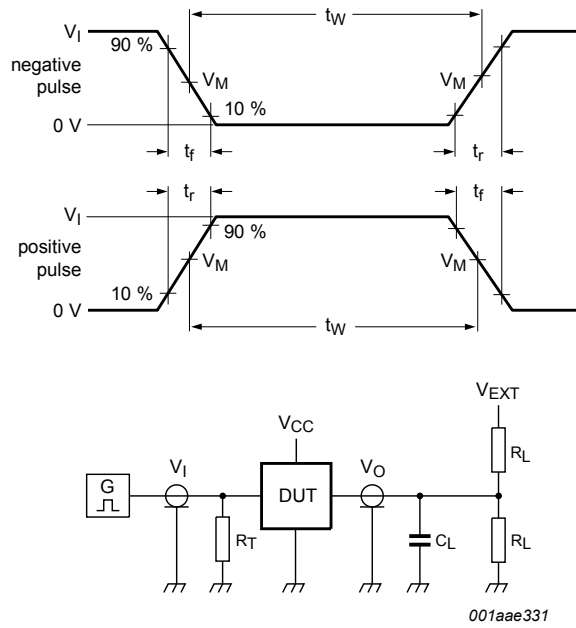






**Table 8. Measurement points**

| $V_{CC}$                    | Input    |                     | Output              |                           |                           |
|-----------------------------|----------|---------------------|---------------------|---------------------------|---------------------------|
|                             | $V_I$    | $V_M$               | $V_M$               | $V_X$                     | $V_Y$                     |
| $V_{CC} \leq 2.7 \text{ V}$ | $V_{CC}$ | $0.5 \times V_{CC}$ | $0.5 \times V_{CC}$ | $V_{OL} + 0.15 \text{ V}$ | $V_{OH} - 0.15 \text{ V}$ |
| $V_{CC} \geq 3.0 \text{ V}$ | 3.0 V    | 1.5 V               | 1.5 V               | $V_{OL} + 0.3 \text{ V}$  | $V_{OH} - 0.3 \text{ V}$  |



Test data is given in [Table 9](#).

Definitions for test circuit:

$R_L$  = Load resistance.

$C_L$  = Load capacitance including jig and probe capacitance.

$R_T$  = Termination resistance should be equal to output impedance  $Z_o$  of the pulse generator.

$V_{EXT}$  = External voltage for measuring switching times.

**Figure 6. Test circuit for measuring switching times**

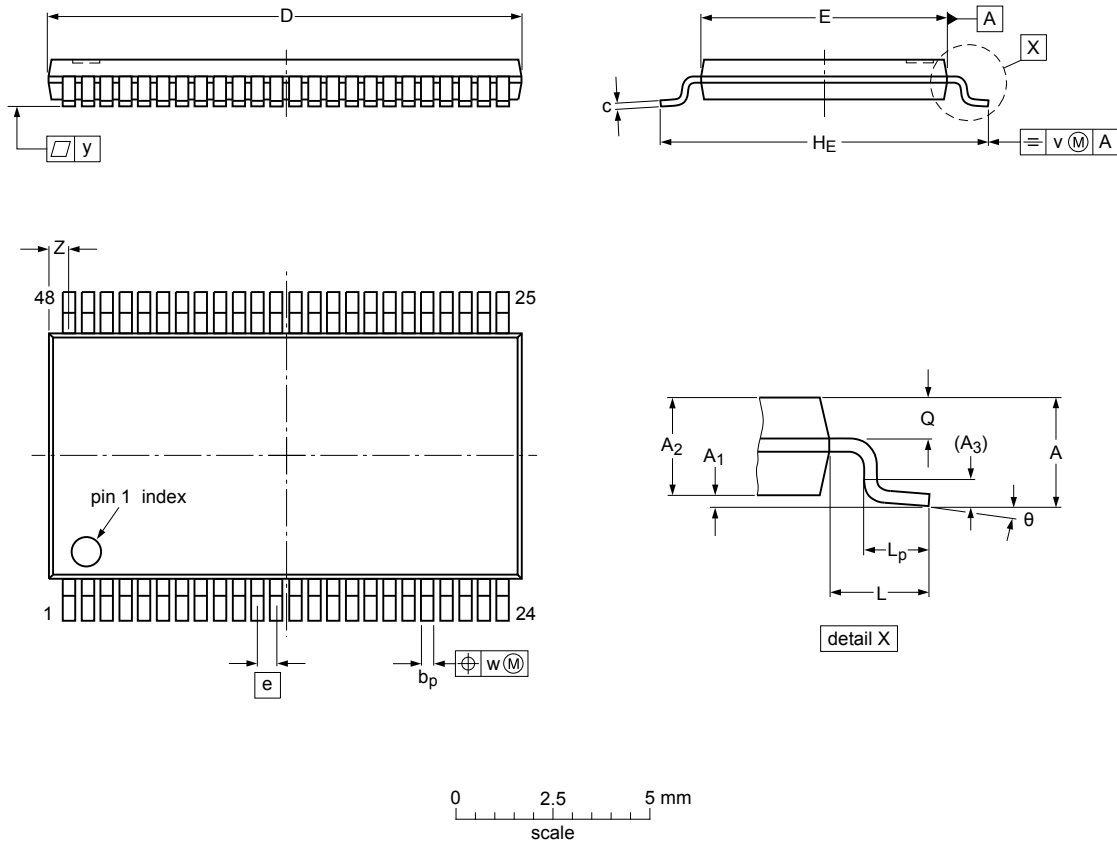
**Table 9. Test data**

| Input                               |               | Load   |               |       |              | $V_{EXT}$          |                          |                    |
|-------------------------------------|---------------|--------|---------------|-------|--------------|--------------------|--------------------------|--------------------|
| $V_I$                               | $f_i$         | $t_W$  | $t_r, t_f$    | $C_L$ | $R_L$        | $t_{PHZ}, t_{PZH}$ | $t_{PLZ}, t_{PZL}$       | $t_{PLH}, t_{PHL}$ |
| 3.0 V or $V_{CC}$ whichever is less | $\leq 10$ MHz | 500 ns | $\leq 2.5$ ns | 50 pF | 500 $\Omega$ | GND                | 6 V or $V_{CC} \times 2$ | open               |

11 Package outline

TSSOP48: plastic thin shrink small outline package; 48 leads; body width 6.1 mm

SOT362-1



Dimensions (mm are the original dimensions)

| Unit | A   | A <sub>1</sub> | A <sub>2</sub> | A <sub>3</sub> | b <sub>p</sub> | c   | D <sup>(1)</sup> | E <sup>(2)</sup> | e   | H <sub>E</sub> | L | L <sub>p</sub> | Q    | v    | w    | y   | Z   | θ  |
|------|-----|----------------|----------------|----------------|----------------|-----|------------------|------------------|-----|----------------|---|----------------|------|------|------|-----|-----|----|
| max  |     | 0.15           | 1.05           |                | 0.28           | 0.2 | 12.6             | 6.2              |     | 8.3            |   | 0.8            | 0.50 |      |      |     | 0.8 | 8° |
| nom  | 1.2 |                |                | 0.25           |                |     |                  |                  | 0.5 |                | 1 |                |      | 0.25 | 0.08 | 0.1 |     |    |
| min  |     | 0.05           | 0.85           |                | 0.17           | 0.1 | 12.4             | 6.0              |     | 7.9            |   | 0.4            | 0.35 |      |      |     | 0.4 | 0° |

Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

sot362-1\_po

| Outline version | References |        |       | European projection | Issue date           |
|-----------------|------------|--------|-------|---------------------|----------------------|
|                 | IEC        | JEDEC  | JEITA |                     |                      |
| SOT362-1        |            | MO-153 |       |                     | 03-02-19<br>13-08-05 |

Figure 7. Package outline SOT362-1 (TSSOP48)

## 12 Abbreviations

Table 10. Abbreviations

| Acronym | Description                                     |
|---------|---|
| BICMOS  | Bipolar Complementary Metal Oxide Semiconductor |
| DUT     | Device Under Test                               |
| ESD     | ElectroStatic Discharge                         |
| MIL     | Military  |
| MM      | Machine Model                                   |
| TTL     | Transistor-Transistor Logic                     |

## 13 Revision history

Table 11. Revision history

| Document ID     | Release date  | Data sheet status     | Change notice | Supersedes      |
|-----------------|---|-----------------------|---------------|-----------------|
| 74ALVT16244 v.5 | 20180202  | Product data sheet    | -             | 74ALVT16244 v.4 |
| Modifications:  | <ul style="list-style-type: none"> <li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> <li>Type number 74ALVT16244DL (SOT370-1 / SSOP48) removed.</li> </ul> |                       |               |                 |
| 74ALVT16244 v.4 | 19981007  | Product specification | -             | 74ALVT16244 v.3 |
| 74ALVT16244 v.3 | 19980213  | Product specification | -             | 74ALVT16244 v.2 |
| 74ALVT16244 v.2 | 19980213  | Product specification | -             | 74ALVT16244 v.1 |
| 74ALVT16244 v.1 | 19960529  | Product specification | -             | -               |

## 14 Legal information

### 14.1 Data sheet status

| Document status <sup>[1][2]</sup> | Product status <sup>[3]</sup> | Definition  |
|-----------------------------------|-------------------------------|---|
| Objective [short] data sheet      | Development                   | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet    | Qualification                 | This document contains data from the preliminary specification.                       |
| Product [short] data sheet        | Production                    | This document contains the product specification.                                     |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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